74LCXH162244

LOW VOLTAGE CMOS 16-BIT BUS BUFFER (3-STATE) WITH 5V TOLERANT INPUTS AND OUTPUTS

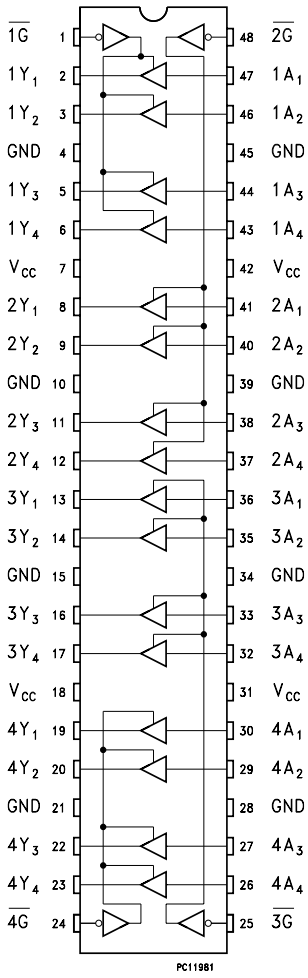
- 5V TOLERANT INPUTS AND OUTPUTS
- HIGH SPEED :
  t_{PD} = 4.4 ns (MAX.) at V_{CC} = 3V
- POWER DOWN PROTECTION ON INPUTS AND OUTPUTS
- SYMMETRICAL OUTPUT IMPEDANCE:
  $|I_{OH}| = I_{OL}$ = 12mA (MIN) at V_{CC} = 3V
- PCI BUS LEVELS GUARANTEED AT 12 mA
- BALANCED PROPAGATION DELAYS:
  $t_{PLH} \cong t_{PHL}$
- 26Ω SERIE RESISTORS IN OUTPUTS
- BUS HOLD PROVIDED ON DATA INPUT
- OPERATING VOLTAGE RANGE:
  V_{CC}(OPR) = 2.0V to 3.6V (1.5V Data Retention)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES H162244
- LATCH-UP PERFORMANCE EXCEEDS 500mA (JESD 17)
- ESD PERFORMANCE:
  HBM > 2000V (MIL STD 883 method 3015);
  MM > 200V

TSSOP

ORDER CODES

PACKAGE	TUBE	T & R
TSSOP		74LCXH162244TTR

PIN CONNECTION



DESCRIPTION

The 74LCX162244 is a low voltage CMOS 16 BIT BUS BUFFER (NON-INVERTED) fabricated with sub-micron silicon gate and double-layer metal wiring C^2MOS technology. It is ideal for low power and high speed 3.3V applications; it can be interfaced to 5V signal environment for both inputs and outputs.

Any n$\overline{G}$ output control governs four BUS BUFFERS. Output Enable input (n$\overline{G}$) tied together gives full 16-bit operation.

When n$\overline{G}$ is LOW, the outputs are on. When n$\overline{G}$ is HIGH, the output are in high impedance state.

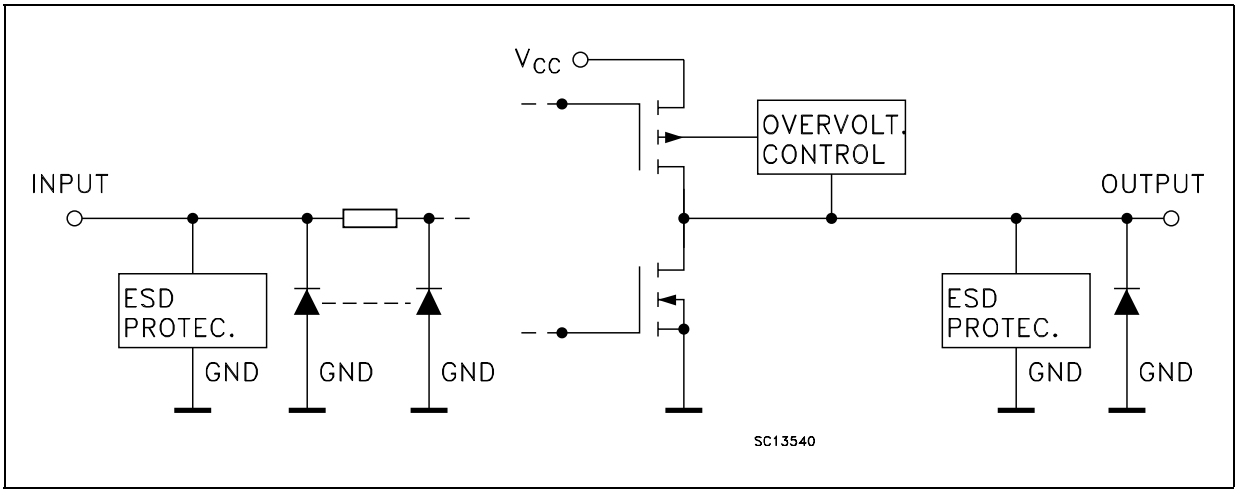
Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

This device is designed to be used with 3 state memory address drivers, etc.

The device circuits is including 26Ω series resistance in the outputs. These resistors permit to reduce line noise in high speed applications.

All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

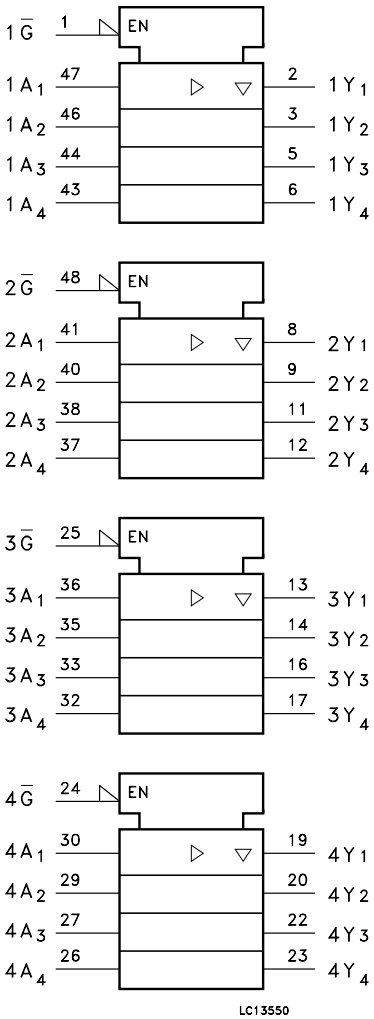
PIN No	SYMBOL	NAME AND FUNCTION
1	$1\overline{G}$	Output Enable Input
2, 3, 5, 6	1Y1 to 1Y4	Data Outputs
8, 9, 11, 12	2Y1 to 2Y4	Data Outputs
13, 14, 16, 17	3Y1 to 3Y4	Data Outputs
19, 20, 22, 23	4Y1 to 4Y4	Data Outputs
24	$4\overline{G}$	Output Enable Input
25	$3\overline{G}$	Output Enable Input
30, 29, 27, 26	4A1 to 4A4	Data Outputs
36, 35, 33, 32	3A1 to 3A4	Data Outputs
41, 40, 38, 37	2A1 to 2A4	Data Outputs
47, 46, 44, 43	1A1 to 1A4	Data Outputs
48	$2\overline{G}$	Output Enable Input
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V_{CC}	Positive Supply Voltage

TRUTH TABLE

INPUTS		OUTPUT
$\overline{G}$	An	Yn
L	L	L
L	H	H
H	X	Z

X : Don't Care
Z : High Impedance

IEC LOGIC SYMBOLS



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage	-0.5 to +7.0	V
V_I	DC Input Voltage	-0.5 to +7.0	V
V_O	DC Output Voltage (OFF State)	-0.5 to +7.0	V
V_O	DC Output Voltage (High or Low State) (note 1)	-0.5 to V_{CC} + 0.5	V
I_{IK}	DC Input Diode Current	- 50	mA
I_{OK}	DC Output Diode Current (note 2)	- 50	mA
I_O	DC Output Current	± 50	mA
I_{CC}	DC Supply Current per Supply Pin	± 100	mA
I_{GND}	DC Ground Current per Supply Pin	± 100	mA
T_{stg}	Storage Temperature	-65 to +150	°C
T_L	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied
1) I_O absolute maximum rating must be observed
2) V_O < GND

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Value	Unit
V_{CC}	Supply Voltage (note 1)	2.0 to 3.6	V
V_I	Input Voltage	0 to 5.5	V
V_O	Output Voltage (OFF State)	0 to 5.5	V
V_O	Output Voltage (High or Low State)	0 to V_{CC}	V
I_{OH}, I_{OL}	High or Low Level Output Current (V_{CC} = 3.0 to 3.6V)	± 12	mA
I_{OH}, I_{OL}	High or Low Level Output Current (V_{CC} = 2.7V)	± 8	mA
T_{op}	Operating Temperature	-55 to 125	°C
dt/dv	Input Rise and Fall Time (note 2)	0 to 10	ns/V

1) Truth Table guaranteed: 1.5V to 3.6V
2) V_{IN} from 0.8V to 2V at V_{CC} = 3.0V

DC SPECIFICATIONS

Symbol	Parameter	Test Condition		Value				Unit
		V_{CC} (V)		-40 to 85 °C		-55 to 125 °C		
				Min.	Max.	Min.	Max.	
V_{IH}	High Level Input Voltage	2.7 to 3.6		2.0		2.0		V
V_{IL}	Low Level Input Voltage				0.8		0.8	V
V_{OH}	High Level Output Voltage	2.7 to 3.6	I_O=-100 µA	V_{CC}-0.2		V_{CC}-0.2		V
		2.7	I_O=-8 mA	2.0		2.0		
		3.0	I_O=-6 mA	2.4		2.4		
			I_O=-12 mA	2.0		2.0		
V_{OL}	Low Level Output Voltage	2.7 to 3.6	I_O=100 µA		0.2		0.2	V
		2.7	I_O=8 mA		0.6		0.6	
		3.0	I_O=6 mA		0.55		0.55	
			I_O=12 mA		0.8		0.8	
I_I	Input Leakage Current	2.7 to 3.6	V_I = 0 to 5.5V		± 5		± 5	µA
$I_{I(HOLD)}$	Input Hold Current	3.0	V_I = 0.8V	75		75		µA
			V_I = 2.0V	-75		-75		
		3.6	V_I = 0 to 3.6V		± 500		± 500	
I_{off}	Power Off Leakage Current	0	V_I or V_O = 5.5V		10		10	µA
I_{OZ}	High Impedance Output Leakage Current	2.7 to 3.6	V_I = V_{IH} or V_{IL} V_O = 0 to V_{CC}		± 5		± 5	µA
I_{CC}	Quiescent Supply Current	2.7 to 3.6	V_I = V_{CC} or GND		20		20	µA
			V_I or V_O= 3.6 to 5.5V		± 20		± 20	
ΔI_{CC}	I_{CC} incr. per Input	2.7 to 3.6	V_{IH} = V_{CC} - 0.6V		500		500	µA

DYNAMIC SWITCHING CHARACTERISTICS

Symbol	Parameter	Test Condition		Value			Unit
		V_{CC} (V)		T_A = 25 °C			
				Min.	Typ.	Max.	
V_{OLP}	Dynamic Low Level Quiet Output (note 1)	3.3	C_L = 50pF V_{IL} = 0V, V_{IH} = 3.3V		0.8		V
V_{OLV}					-0.8		

1) Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH to LOW or LOW to HIGH. The remaining output is measured in the LOW state.

AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test Condition				Value				Unit
		V_{CC} (V)	C_L (pF)	R_L (Ω)	$t_s = t_r$ (ns)	-40 to 85 °C		-55 to 125 °C		
						Min.	Max.	Min.	Max.	
t_{PLH} t_{PHL}	Propagation Delay Time	2.7	50	500	2.5	1.5	5.6	1.5	6.5	ns
		3.0 to 3.6				1.5	4.4	1.5	5.1	
t_{PZL} t_{PZH}	Output Enable Time	2.7	50	500	2.5	1.5	6.3	1.5	7.2	ns
		3.0 to 3.6				1.5	5.9	1.5	6.8	
t_{PLZ} t_{PHZ}	Output Disable Time	2.7	50	500	2.5	1.5	6.3	1.5	7.2	ns
		3.0 to 3.6				1.5	5.9	1.5	6.8	
t_{OSLH} t_{OSHL}	Output To Output Skew Time (note1, 2)	3.0 to 3.6	50	500	2.5		1.0		1.0	ns

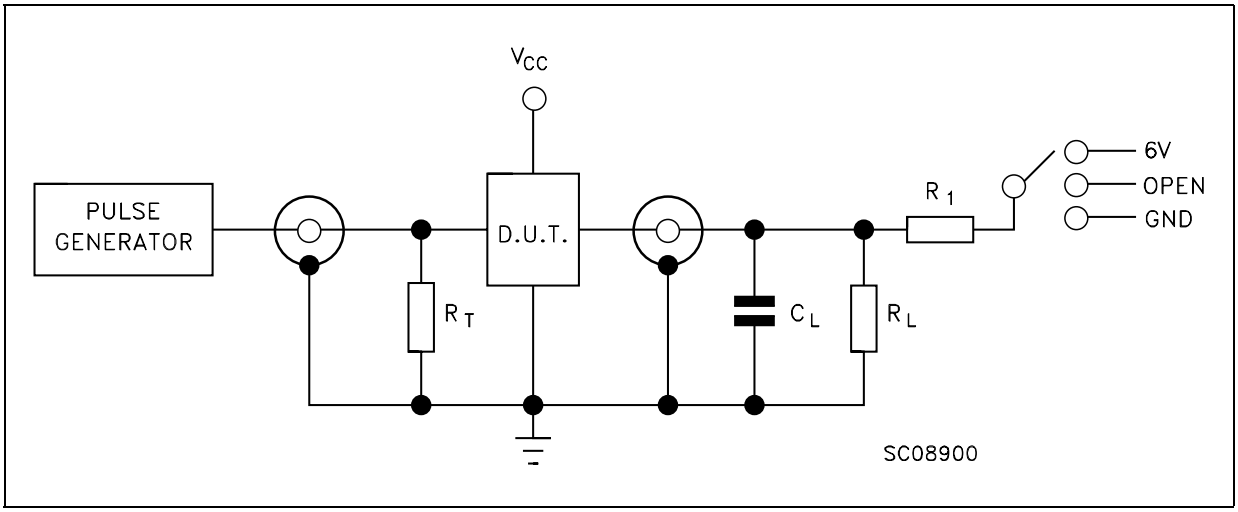
1) Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW ($t_{OSLH} = | t_{PLHm} - t_{PLHn} |$, $t_{OSHL} = | t_{PHLm} - t_{PHLn} |$)
2) Parameter guaranteed by design

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Test Condition		Value			Unit
		V_{CC} (V)		T_A = 25 °C			
				Min.	Typ.	Max.	
C_{IN}	Input Capacitance				4		pF
C_{OUT}	Output Capacitance				10		pF
C_{PD}	Power Dissipation Capacitance (note 1)	3.3	f_{IN} = 10MHz V_{IN} = 0 or V_{CC}		50		pF

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/16$ (per circuit)

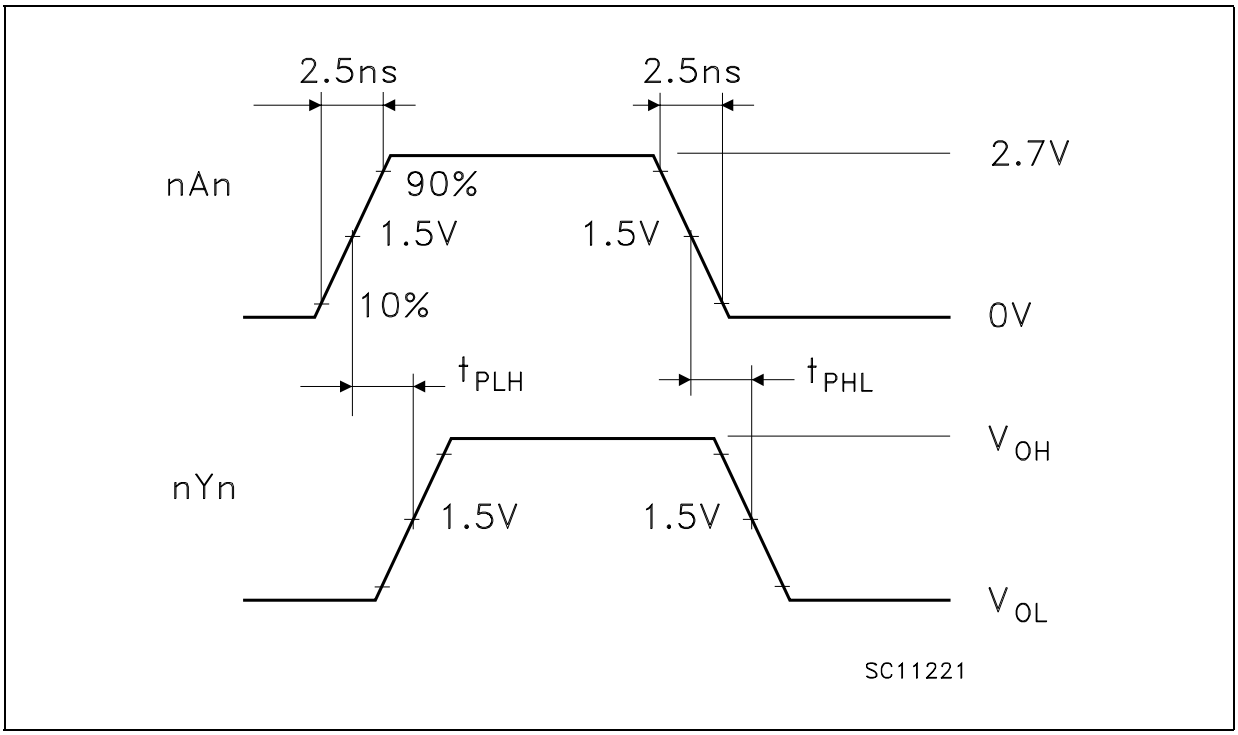
TEST CIRCUIT



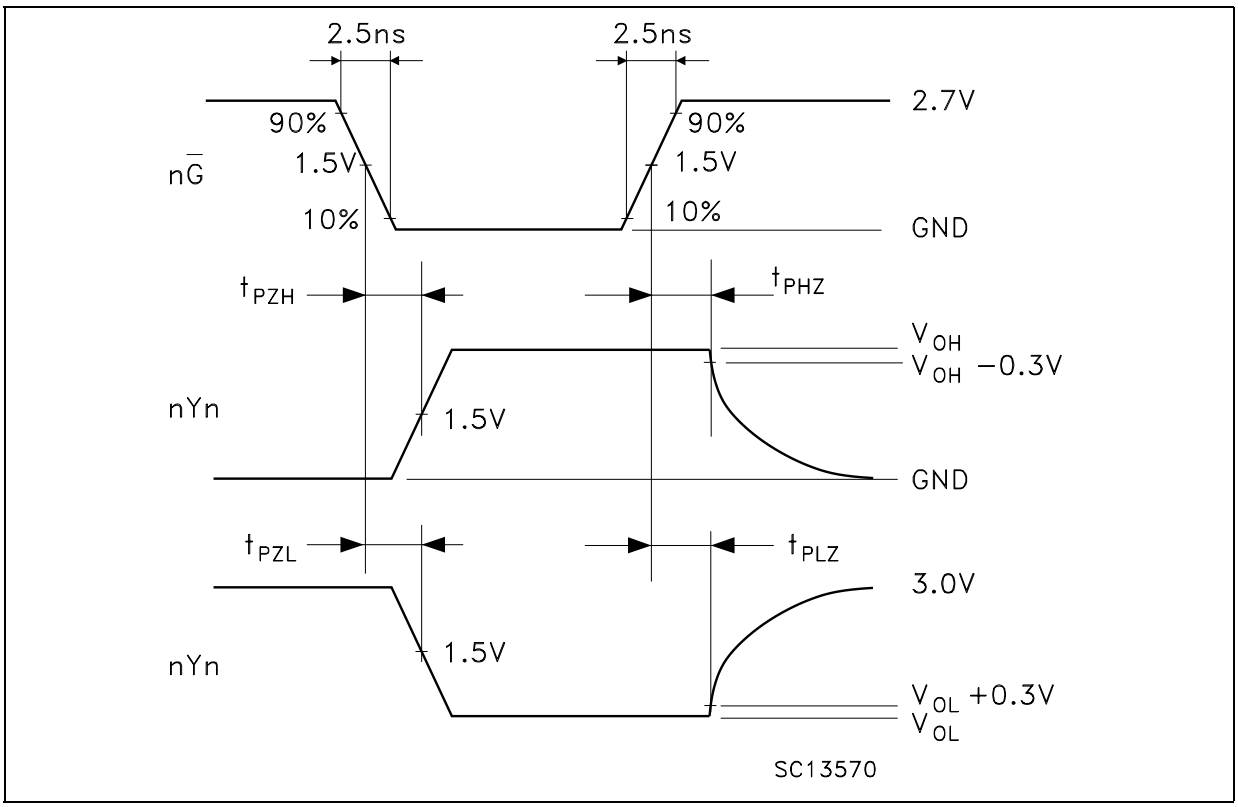
TEST	SWITCH
t_{PLH}, t_{PHL}	Open
t_{PZL}, t_{PLZ}	6V
t_{PZH}, t_{PHZ}	GND

C_L = 50 pF or equivalent (includes jig and probe capacitance)
R_L = R1 = 500Ω or equivalent
R_T = Z_{OUT} of pulse generator (typically 50Ω)

WAVEFORM 1 : PROPAGATION DELAYS (f=1MHz; 50% duty cycle)

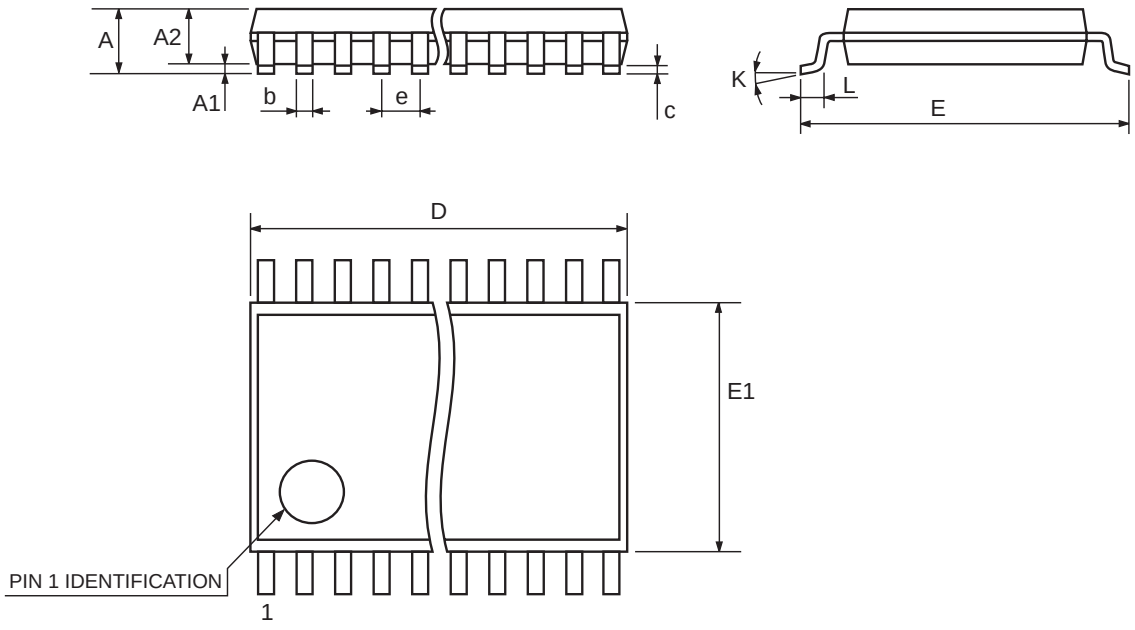


WAVEFORM 2 : OUTPUT ENABLE AND DISABLE TIME (f=1MHz; 50% duty cycle)



TSSOP48 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2		0.9			0.035	
b	0.17		0.27	0.0067		0.011
c	0.09		0.20	0.0035		0.0079
D	12.4		12.6	0.488		0.496
E		8.1 BSC			0.318 BSC	
E1	6.0		6.2	0.236		0.244
e		0.5 BSC			0.0197 BSC	
K	0°		8°	0°		8°
L	0.50		0.75	0.020		0.030



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Tape & Reel TSSOP48 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			330			12.992
C	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
T			30.4			1.197
Ao	8.7		8.9	0.343		0.350
Bo	13.1		13.3	0.516		0.524
Ko	1.5		1.7	0.059		0.067
Po	3.9		4.1	0.153		0.161
P	11.9		12.1	0.468		0.476